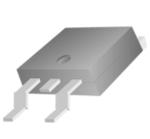
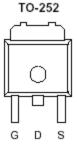
N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe DPAK saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)} m(\Omega)$	I _D (A)		
30	$59 @ V_{GS} = 10V$	24		
	$88 @ V_{GS} = 4.5V$	20		





Top View

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C UNLESS OTHERWISE NOTED)				
Parameter			Limit	Units
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Voltage		V _{c8}	±20	v
Continuous Drain Current ^a	$T_{\rm C}=25^{\circ}{\rm C}$	I _D	24	•
Pulsed Drain Current ^b		I _{DM}	75	А
Continuous Source Current (Diode Conduction) ^a		Is	30	Α
Power Dissipation ^a	$T_{C}=25^{\circ}C$	PD	50	W
Operating Junction and Storage Temperature Range		TJ, Tstg	-55 to 175	°C

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Maximum	Units	
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	50	°C/W	
Maximum Junction-to-Case	$R_{\theta JC}$	3.0	°C/W	

1

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

SPECIFICATIONS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)							
Deverse to v	Samula	Test Conditions	Limits			TT*4	
Parameter	Symbol	mbol Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1		2.3	V	
Gate-Body Leakage	Igss	$V_{DS} = 0 V, V_{GS} = 20 V$			±100	nA	
Zara Cata Valtaga Drain Current	Idss	$V_{DS} = 24 V, V_{GS} = 0 V$	1		1	uA	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current ^A	ID(on)	$V_{DS} = 5 V, V_{GS} = 10 V$	34			А	
		$V_{GS} = 10 \text{ V}, \text{ ID} = 12 \text{ A}$			59		
Drain-Source On-Resistance ^A	rDS(on)	$V_{GS} = 4.5 V$, $I_D = 10 A$			88	mΩ	
Forward Tranconductance ^A	gís	$V_{DS} = 15 \text{ V}, I_D = 12 \text{ A}$		22		S	
Diode Forward Voltage	Vsd	$I_{S} = 24 \text{ A}, V_{GS} = 0 \text{ V}$		1.1		V	
Dynamic ^b							
Total Gate Charge	Qg	$V_{DS} = 15 V$, $V_{GS} = 4.5 V$,		2.2			
Gate-Source Charge	Qgs			0.5		nC	
Gate-Drain Charge	Qgd	$I_D = 10 A$		0.8		7	
Input Capacitance	Ciss	$\mathbf{X} = 15 \mathbf{X} \mathbf{X} = 0 \mathbf{X}$		720			
Output Capacitance	Coss	$V_{DS} = 15 V, V_{GS} = 0 V,$ f = 1MHz		165		pF	
Reverse Transfer Capacitance	Crss			60		1	
Turn-On Delay Time	td(on)			16			
Rise Time	tr	V_{DD} = 25 V, R_L = 25 Ω , I_D = 24 A,		5		nS	
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = 10 V$		23		115	
Fall-Time	tf			3			

Notes

- a. Pulse test: $PW \le 300$ uty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Typical Electrical Characteristics (N-Channel)

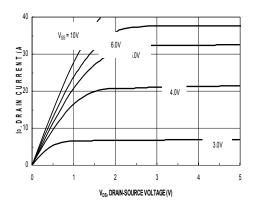


Figure 1. On-Region Characteristics

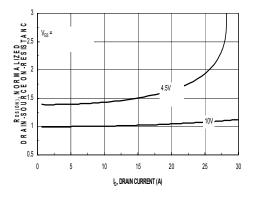


Figure 3. On Resistance Vs Vgs Voltage

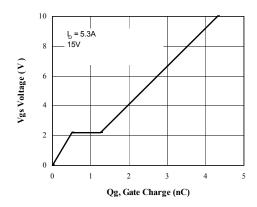


Figure 5. Gate Charge Characteristics

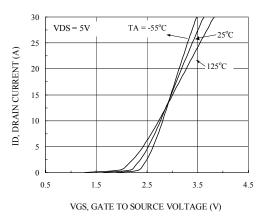


Figure 2. Body Diode Forward Voltage Variation

with Source Current and Temperature

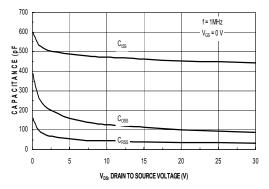


Figure 4. Capacitance Characteristics

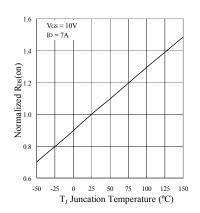


Figure 6. On-Resistance Variation with Temperature

Typical Electrical Characteristics (N-Channel)

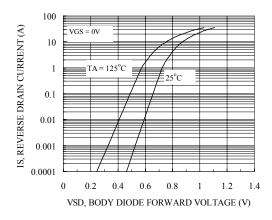


Figure 7. Transfer Characteristics

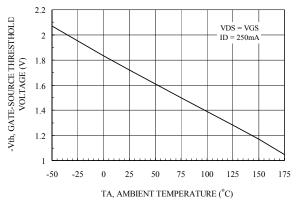


Figure 9. Vth Gate to Source Voltage Vs Temperature

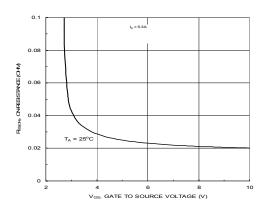


Figure 8. On-Resistance with Gate to Source Voltage

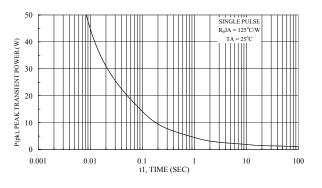
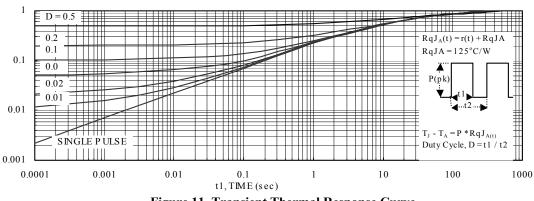


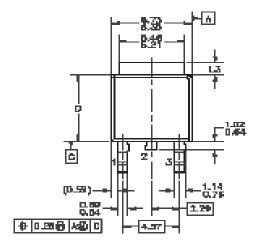
Figure 10. Single Pulse Maximum Power Dissipation

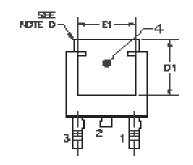


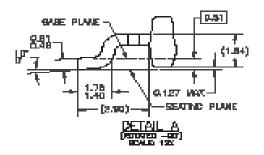
Normalized Thermal Transient Junction to Ambient

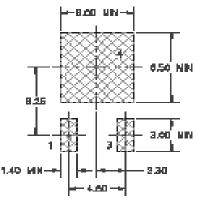


Package Information

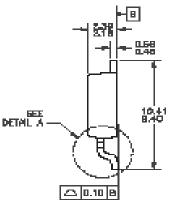








LAND PATTERN RECOMMENDATION



- NOTES: UNLESS OTHERWISE SPECIFIED
 - ALL DIVENERAS ARE IN NULLHETERS. 骨目

 - THIS PACIONCE CONFORME TO LEDEC, TO-262, IBBUE C, VARIATION AA IN AE, DATED NOW 1989. Dimensioning and toleranging per C)

 - ABNE Y14,000-1884. HEAT SINK TOP EDGE COLLD BE IN CHANFERED CORNERS OR EDGE PROTRASION. DIMENSIONE L3,0,61401 TABLE: D)
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	ALL REPORTS	
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5	4.422 (1994)	
		4.47